


**SOLUTION  
EXERXISE (O-I)**

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1. Covalent network solids are → [SiO<sub>2</sub>, Diamond, Si, AlN & SiC]

2. (C)

7. Factual

8. Factual

9. For triclinic system

$$a \neq b \neq c \quad \& \quad \alpha \neq \beta \neq \gamma = 90^\circ,$$

Hence most unsymmetrical.

10. In match box

$$a \neq b \neq c \quad \& \quad \alpha = \beta = \gamma = 90^\circ,$$

Hence orthorhombic geometry

11. For hexagonal crystal system

$$a = b \neq c \quad \& \quad \alpha = \beta = 90^\circ \quad \& \quad \gamma = 120^\circ$$

14. The distance between 2 nearest neighbor in B.C.C. is  $\frac{\sqrt{3}a}{2}$

$$\text{i.e. } \frac{\sqrt{3} \times 5.2}{2}$$

$$\text{i.e. } 4.5\text{\AA}$$

15. In BCC

$$\sqrt{3}a = 4r$$

$$\text{Fraction of edge occupied by atoms} = \frac{2r}{a}$$

$$= \frac{2r}{\frac{4}{\sqrt{3}}r} = \frac{\sqrt{3}}{2}$$

16. For B.C.C.

$$r = \frac{\sqrt{3}a}{4} = \frac{\sqrt{3} \times 286}{4} \quad \text{i.e. } r = 124 \text{ pm}$$

20. Factual

22. The shortest distance between 1<sup>st</sup> & V<sup>th</sup> layer of HCP arrangement is 2C

$$\text{i.e. } 2 \times \left( \sqrt{\frac{2}{3}} \times 4r \right)$$



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$$\text{i.e. } 8\sqrt{\frac{2}{3}}r$$

23. Volume of HCP unit CsCl = (Area of Base × height)



$$\text{i.e. } \left(6 \times \frac{\sqrt{3}}{4} \times a^2\right) \times 2\sqrt{\frac{2}{3}}r$$

$$\begin{aligned} \text{i.e. } & \frac{6\sqrt{3}}{4} \times (2r)^2 + 2\sqrt{\frac{2}{3}} \times (2r) \\ &= 24\sqrt{2}r^3. \end{aligned} \quad (\text{As } a = 2r)$$

$$24. \frac{\rho_{\text{fcc,Fe}}}{\rho_{\text{bcc,Fe}}} = \frac{\pi / 3\sqrt{2}}{\sqrt{3}\pi / 8}$$

25. Volume occupied by atoms in an bcc unit cell is -

$$2 \times \frac{4}{3}\pi r^3 = \left[ \frac{2 \times \frac{M}{N_A}}{\rho} \right] \times \frac{\sqrt{3}\pi}{8}$$

26. It is formed by 4 spheres the centres of which form a regular tetrahedron

27. For tetrahedral voids

$$r = 0.225 R$$

& for octahedral voids

$$r = 0.414 R$$

⇒ Size of an octahedral void formed in a closed packed lattice is larger as compared to tetrahedral void.

28. Number of atom X =  $7 \times \frac{1}{8}$

$$\text{Number of atom } y = 1$$

Formula of compound will be  $(X_7 Y_8)$

29. For -----ABCABC----- closed packing sequence, it forms C.C.P / F.C.C.

Number of tetrahedral voids is twice the number of atoms in the unit cell.

Number of tetrahedral void =  $2 \times Z$

Number of octahedral void =  $Z$

30. Number of atom A = 6



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$$\text{Number of atom C} = \frac{2}{3} \times 6 \text{ i.e. } 4$$

Formula of compounds is  $(A_3C_2)$

31. For NaCl

$$2(r_{Na^+} + r_{Cl^-}) = a$$

$$\Rightarrow 2x + 2y = a$$

32. For F.C.C. of  $M^+X^-$   $2(r_{M^+} + r_{X^-}) = 7.2$

$$\Rightarrow 2 \times 1.6 + 2r_{X^-} = 7.2 \quad \Rightarrow r_{X^-} = 2\text{\AA}$$

33. 1 mole i.e. 58.5 g NaCl contains  $\frac{N_A}{4}$  unit cells

$$\Rightarrow 1 \text{ gm cubic crystal of NaCl contains } \left( \frac{N_A}{58.5 \times 4} \right) \text{ unit cells}$$

34. For compounds (XY) for which crystallizes in 8 : 8 lattice.

$$\Rightarrow r_{X^+} + r_{Y^-} \frac{\sqrt{3}}{2} a$$

$$\Rightarrow r_{X^+} \left( \frac{\sqrt{3}}{2} \times 480 - 225 \right)$$

$$\Rightarrow r_{X^+} = 190.68 \text{ pm}$$

35. Number of  $Cs^+ \rightarrow 8 \times \frac{1}{8} \text{ i.e. } 1$

Number of  $Cl^- \rightarrow 1$

36. Factual

37. For ZnS type structure  $\left( \frac{r_{Zn^{+2}}}{r_{S^{-2}}} \square .402 \right)$  it is a 4 : 4 coordination number compound.

$$\Rightarrow \frac{r_{A^+}}{r_{B^-}} = 0.225$$

$$\Rightarrow \frac{22.5}{r_{B^-}} = 0.225$$

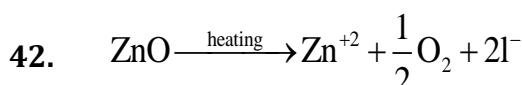
$$\Rightarrow r_{B^-} = 100 \text{ pm}$$

38. For  $CaF_2 \rightarrow$  Coordination number of cation & Anion is 8 : 4

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& For CsCl → coordination number of cation & Anion is 8 : 8

39. Schottky defect is shown by ionic substances in which the cation & Anion are of almost similar sizes.
40. Schottky defect is basically a vacancy defect in ionic solids. In order to maintain electrical neutrality, the number of missing cation & anions are equal.
41. Factual



So, strongly heated ZnO crystal can conduct electricity, this is due to movement of electrons in the anion vacancies.